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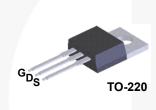
FDP3672

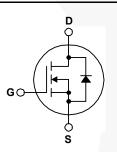
N-Channel PowerTrench[®] MOSFET 105 V, 41 A, 33 m Ω

Features

- $R_{DS(on)}$ = 25 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 41 A
- $Q_{G(tot)} = 28 \text{ nC} (Typ.) @ V_{GS} = 10 \text{ V}$
- Low Miller Charge
- Low Q_{rr} Body Diode
- Optimized Efficiency at High Frequencies
- UIS Capability (Single Pulse and Repetitive Pulse)

Formerly developmental type 82760





Motor drives and Uninterruptible Power Supplies

MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	FDP3672	Unit
V _{DSS}	Drain to Source Voltage	105	V
V _{GS}	Gate to Source Voltage	±20	V
ID	Drain Current		
	Continuous ($T_C = 25^{\circ}C$, $V_{GS} = 10V$)	41	A
	Continuous ($T_c = 100^{\circ}C$, $V_{GS} = 10V$)	31	A
	Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, $R_{\theta JA} = 62^{\circ}C/W$)	5.9	A
	Pulsed	Figure 4	A
E _{AS}	Single Pulse Avalanche Energy (Note 1)	48	mJ
P _D	Power dissipation	135	W
	Derate above 25°C	0.9	W/°C
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C

Applications

Consumer Appliances

Synchronous Rectification

Battery Protection Circuit

· Micro Solar Inverter

Thermal Characteristics

$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.11	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max. (Note 2)	62	°C/W

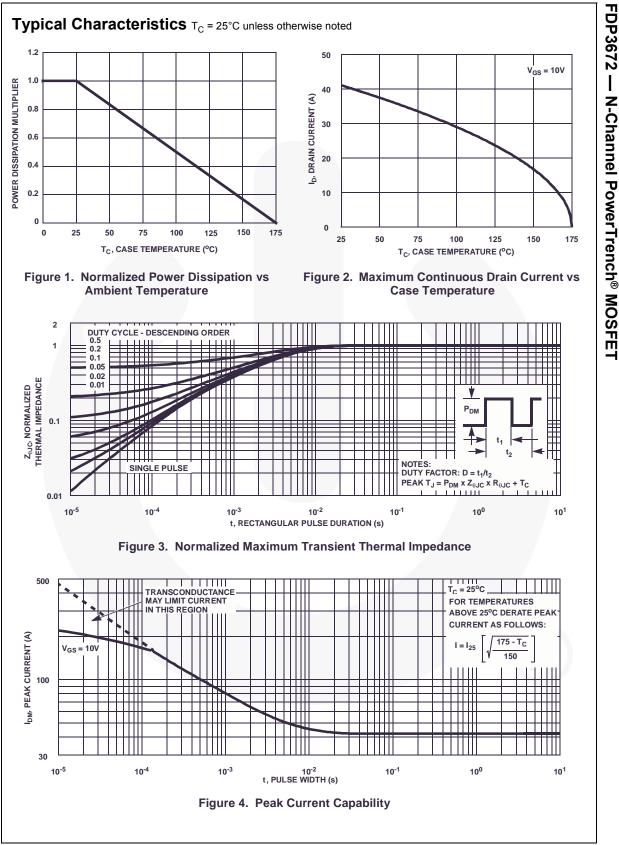
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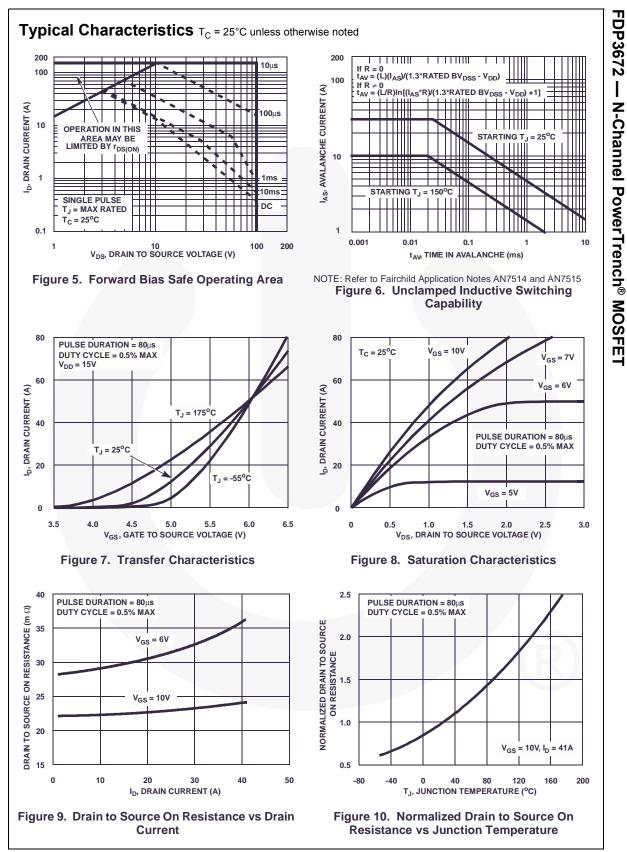
November 2013

Device Marking FDP3672		Device Package Reel Size		Reel Size	Tape Width N/A		Quantity 50 units	
		FDP3672	TO-220 Tube					
Electric	al Char	acteristics T _c = 25°C	cunless otherwis	e noted				
Symbol		Parameter	Test	Conditions	Min	Тур	Max	Unit
Off Chara	cteristic	S						
B _{VDSS}	Drain to S	Source Breakdown Voltage	I _D = 250μA,	$V_{GS} = 0V$	105	-	-	V
	Zara Cat	Valtage Drein Current	V _{DS} = 80V		-	-	1	^
IDSS	Zero Gale	e Voltage Drain Current	$V_{GS} = 0V$	$V_{GS} = 0V \qquad T_{C} = 150^{\circ}C$		-	250	μA
I _{GSS}	Gate to Source Leakage Current		V _{GS} = ±20V	$V_{GS} = \pm 20V$		-	±100	nA
On Chara	cteristic	s						
		ource Threshold Voltage	$V_{GS} = V_{DS},$	$l_{p} = 250 \mu A$	2	-	4	V
V _{GS(TH)}		saloo misonola voltage	$V_{GS} - V_{DS},$ $I_D = 41A, V_C$		-	0.025	0.033	v
			$I_{\rm D} = 21$ A, V ₀		-	0.020	0.055	_
r _{DS(ON)}	Drain to S	Source On Resistance	$I_{\rm D} = 41$ A, V ₀		_			Ω
			$T_{\rm C} = 175^{\circ}{\rm C}$			0.063	0.070	
Dynamic	Characte	aristics						
						1670	-	~F
C _{ISS}	Input Cap	apacitance	V _{DS} = 25V,	V _{GS} = 0V,		240	-	pF pF
C _{oss}	-	Transfer Capacitance	f = 1MHz			55	-	pF
C _{RSS} Q _{g(TOT)}		e Charge at 10V	V _{GS} = 0V to	10V	-	28	37	nC
Q _{g(TH)}		d Gate Charge	$V_{GS} = 0V$ to	a) (-	3.9	5	nC
Q _{gs}		ource Gate Charge		$2V$ $V_{DD} = 50V$ $I_D = 41A$	-	12	-	nC
Q _{gs2}		rge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	8.0	-	nC
Q _{gd}		rain "Miller" Charge		, i i i i i i i i i i i i i i i i i i i	-	6.5	-	nC
	Switchir	Characteristics	1010					
	-	ng Characteristics (V	GS = 10V		-	1	00	
t _{ON}	Turn-On T				-	-	90	ns
t _{d(ON)}	Rise Time	Delay Time		44.0		12 48	-	ns
t _r	_	p Delay Time		$V_{DD} = 50V, I_D = 41A$ $V_{GS} = 10V, R_{GS} = 11.0\Omega$		24	-	ns ns
t _{d(OFF)} t _f	Fall Time		· GS = 101,	1.62 - 11.011	-	24	_	ns
t _{OFF}	Turn-Off 1	Time			-	-	77	ns
Drain-Soເ	irce Diod	de Characteristics						
V _{SD}	Source to	Drain Diode Voltage	I _{SD} = 41A		-	-	1.25	V
- 90	Source to Drain Diode Voltage	I _{SD} = 21A			-	1.0	V	
t _{rr}		Recovery Time		$II_{SD}/dt = 100A/\mu s$	-	-	39	ns
Q _{RR}	Reverse F	Recovered Charge	I _{SD} = 41A, c	II _{SD} /dt =100A/μs	-	-	42	nC

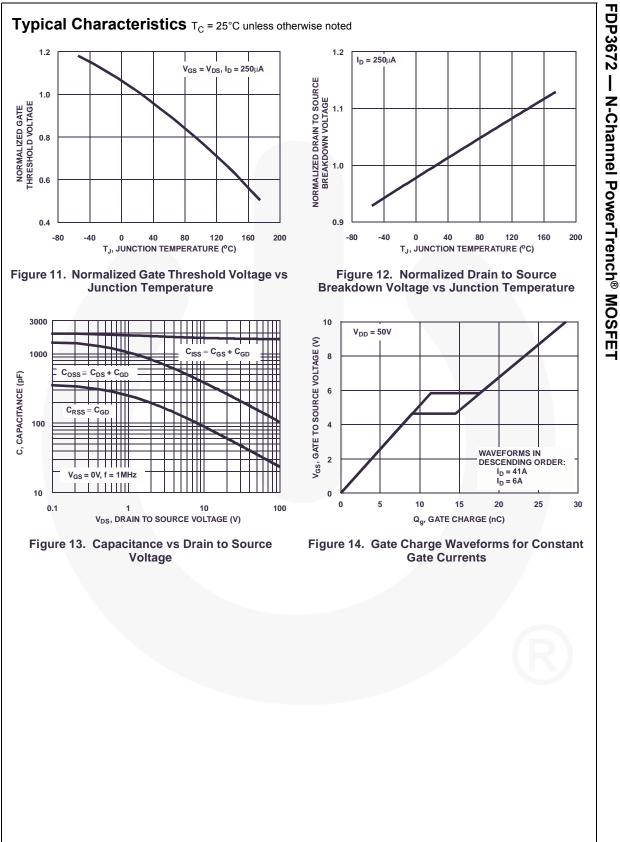
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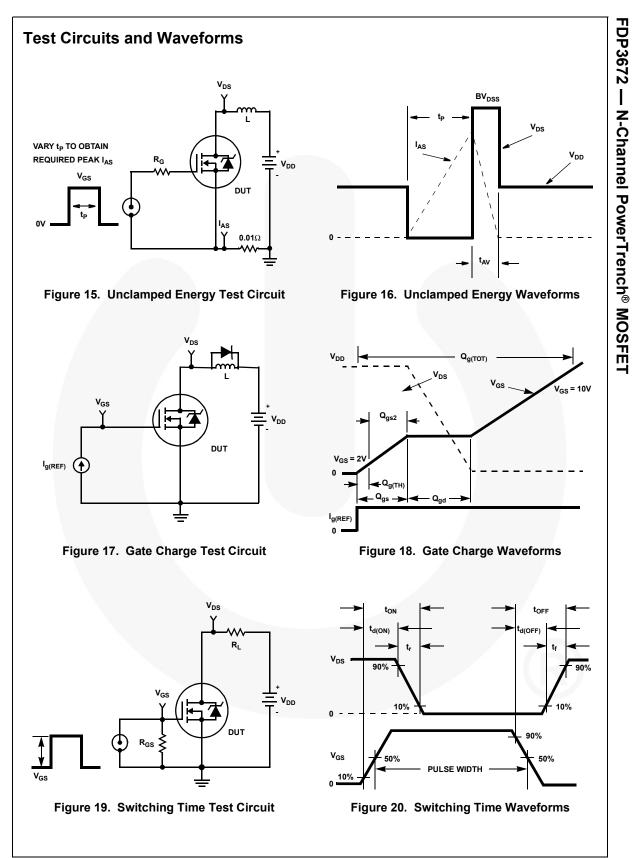


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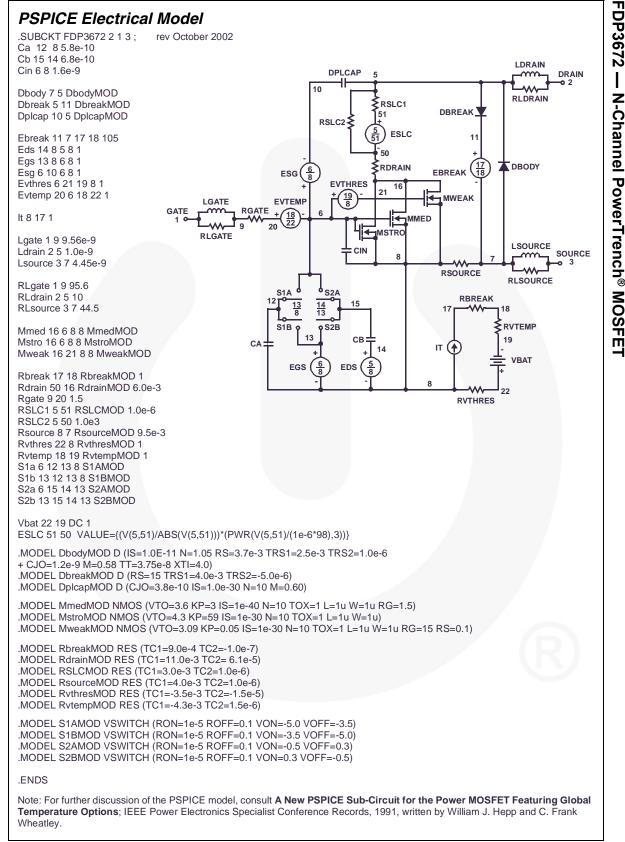


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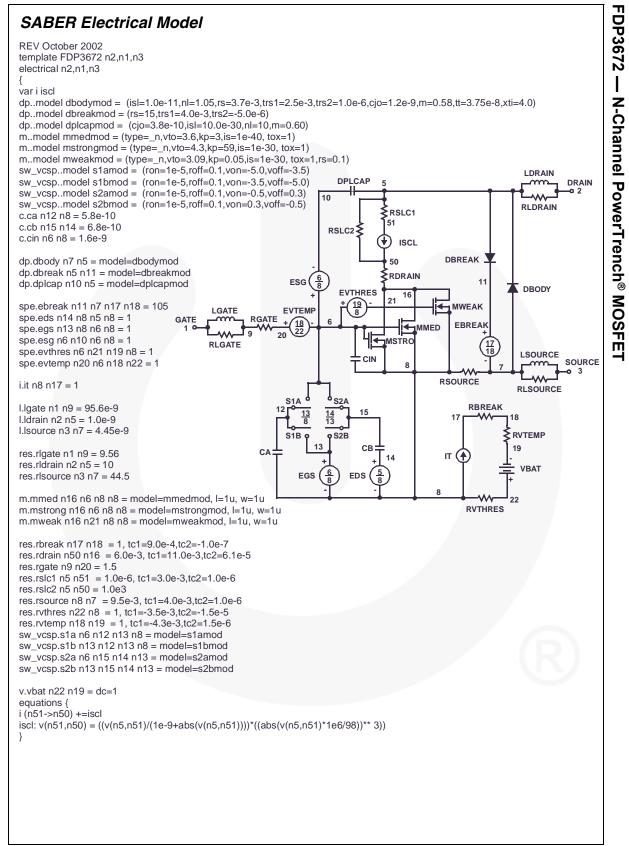


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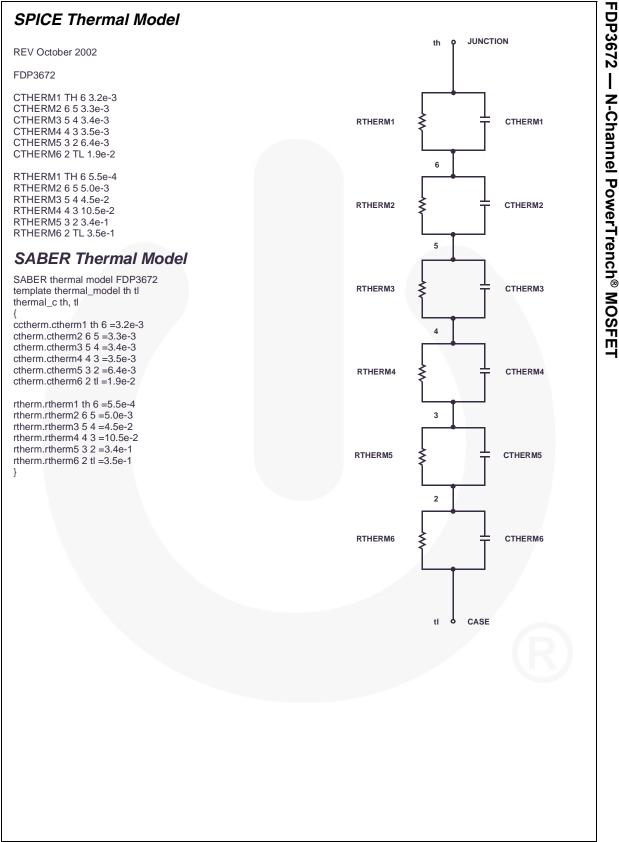


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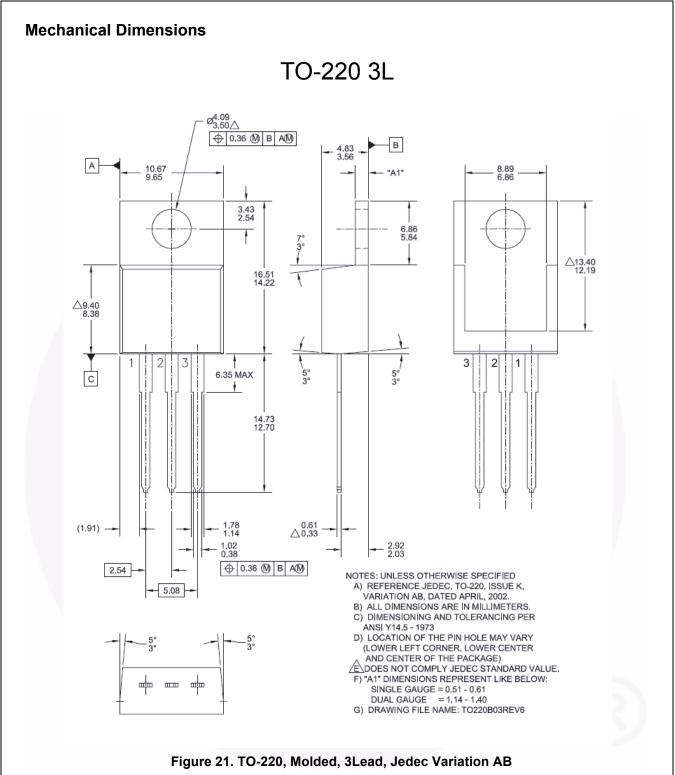


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Dimension in Millimeters



Obsolete

Not In Production

Rev. 166

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